MMBTA63-64

PNP SILICON TRANSISTOR

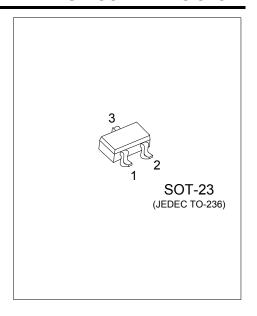
DARLINGTON TRANSISTOR

■ DESCRIPTION

The UTC MMBTA63-64 is a Darlington transistor.

■ FEATURES

- * Collector-Emitter Voltage: V_{CES} = -30V
- * Collector current up to -1.2A
- * Collector Dissipation: P_C = 625 mW



■ ORDERING INFORMATION

Ordering Number		Darling	Pin Assignment			Deelsing	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MMBTA63L-AE3-R	MMBTA63G-AE3-R	SOT-23	В	E	С	Tape Reel	
MMBTA64L-AE3-R	MMBTA64G-AE3-R	SOT-23	В	Е	С	Tape Reel	

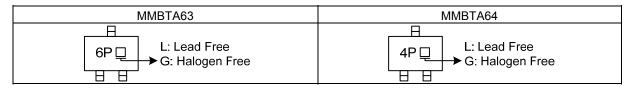
Note: Pin Assignment: B: Base E: Emitter C: Collector

MMBTA63G-AE3-R

(1)Packing Type (1) R: Tape Reel

(2)Package Type (2)Package Type (3)Green Package (3) G: Halogen Free and Lead Free, L: Lead Free

MARKING



<u>www.unisonic.com.tw</u> 1 of 3

■ **ABSOLUTE MAXIMUM RATING** (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	V_{CBO}	-30	V
Collector-Emitter Voltage	V_{CES}	-30	V
Emitter-Base Voltage	V_{EBO}	-10	V
Collector Dissipation (T _C =25°C)	Pc	350	mW
Collector Current	Ic	-1.2	Α
Junction Temperature	T_J	+150	°C
Operating Temperature Range	T _{OPR}	-40 ~ +150	°C
Storage Temperature	T _{STG}	-40 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Breakdown Voltage		BV _{CES}	I _C =-100μA, I _B =0	-30			V
Collector CutOff Current		I _{CBO}	V _{CB} =-30V, I _E =0			-100	nA
Emitter CutOff Current		I _{EBO}	V _{EB} =-10V, I _C =0			-100	nA
DC Current Gain	MMBTA63	h _{FE}	\\ - 5\\ \ - 40ma	5000			
	MMBTA64		V_{CE} =-5V, I_{C} =-10mA	10000			
	MMBTA63		V _{CE} =-5V, I _C =-100mA	10000			
	MMBTA64			20000			
Collector-Emitter Saturation Voltage		V _{CE(SAT)}	I _C =-100mA, I _B =-0.1mA			-1.5	V
Base-Emitter on Voltage		$V_{BE(ON)}$	V _{CE} =-5V, I _C =-100mA			-2.0	V
Current Gain Bandwidth Product		f_T	V _{CE} =-5V, I _C =-10mA, f=100MHz	125			MHz

Note: Pulse test: Pulse Width <300µs, Duty Cycle<2%.

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